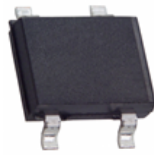


1.0A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER
Features

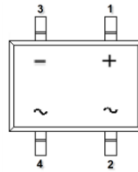
- Glass Passivated Die Construction
- Low Forward Voltage Drop, High Current Capability
- Surge Overload Rating to 50A Peak
- Designed for Surface Mount Application
- UL Listed Under Recognized Component Index, File Number E94661
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

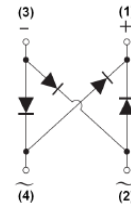
- Case: DF-S
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Tin. Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Case
- Weight: 0.38 grams (Approximate)



Top View



Pin Diagram



Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DFxS	DF-S	50/Tube
DFxS-T	DF-S	1500/Tape & Reel, 13-inch

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information


- DII = Manufacturers' Code Marking
- DFxxxS = Product Type Marking Code, ex: DF10S
- YWW = Date Code Marking
- Y = Last Digit of Year (ex: 6 for 2016)
- WW = Week Code (01 to 52)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	Unit
Peak Repetitive Reverse Voltage	V _{RMM}	50	100	200	400	600	800	1000	V
Working Peak Reverse Voltage	V _{RWM}								
DC Blocking Voltage	V _R								
RMS Reverse Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Average Forward Rectified Current @ T _A = +40°C	I _O	1.0							A
Non-Repetitive Peak Forward Surge Current, 8.3 ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	50							A

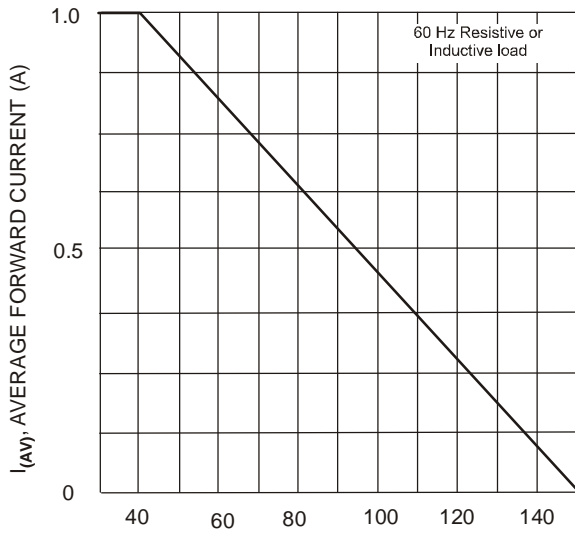
Thermal Characteristics

Characteristic	Symbol	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	Unit
Typical Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	40							°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150							°C

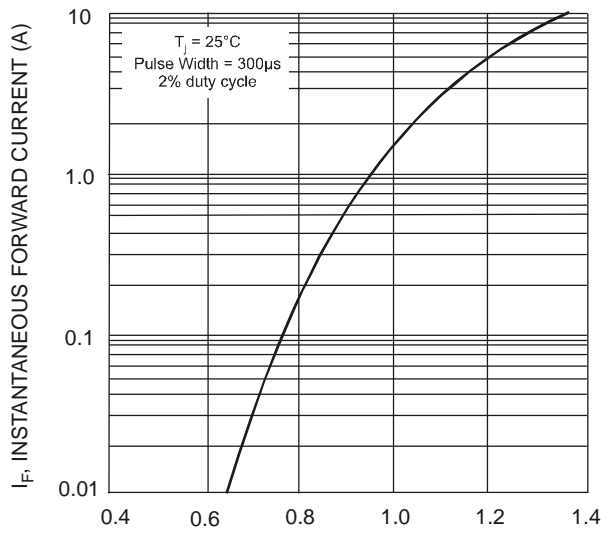
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	Unit
Forward Voltage (Per Element) @ I _F = 1.0A	V _{FM}	1.1							V
Peak Reverse Current at Rated @ T _A = +25°C	I _{RM}	10							μA
DC Blocking Voltage (Per Element) @ T _A = +125°C		500							
I ² t Rating for Fusing (t<8.3ms)	I ² t	10.4							A ² s
Typical Total Capacitance (Per Element) (Note 5)	C _T	25							pF

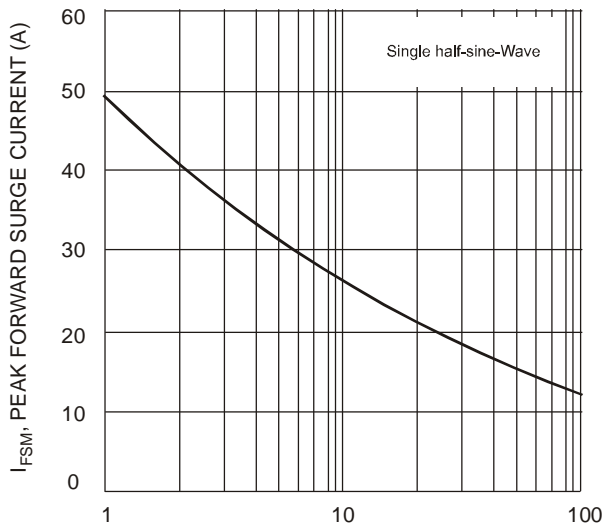
Notes: 5. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
6. Thermal resistance, junction to ambient, measured on PC board with 5.0mm² (0.03mm thick) land areas.



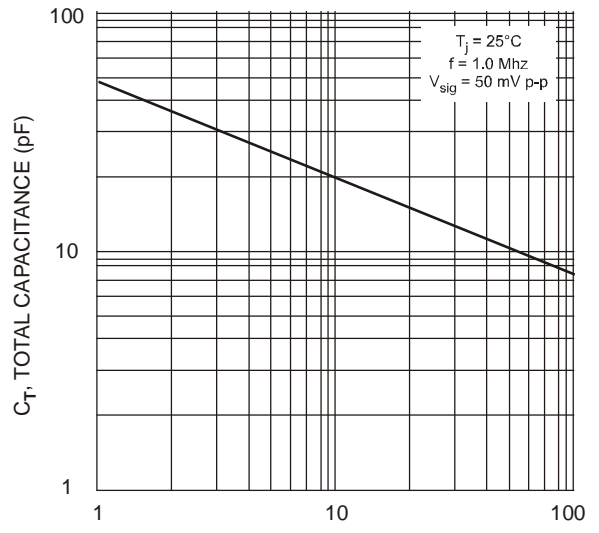
T_A , AMBIENT TEMPERATURE (°C)
Fig. 1 Output Current Derating Curve



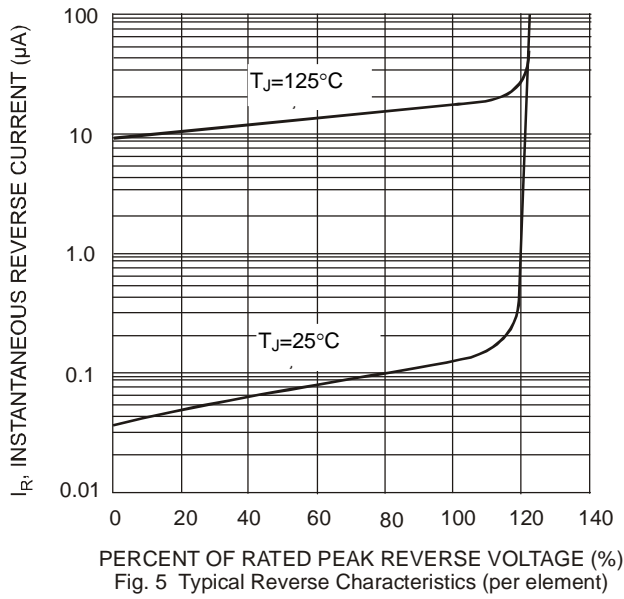
V_F , INSTANTANEOUS FORWARD VOLTAGE (V)
Fig. 2 Typical Forward Characteristics (per element)



NUMBER OF CYCLES AT 60 Hz
Fig. 3 Max Non-Repetitive Peak Forward Surge Current

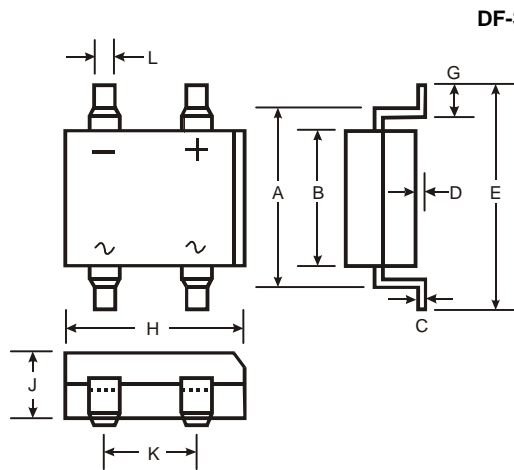


V_R , REVERSE VOLTAGE (V)
Fig. 4 Typical Total Capacitance (per element)



Package Outline Dimensions

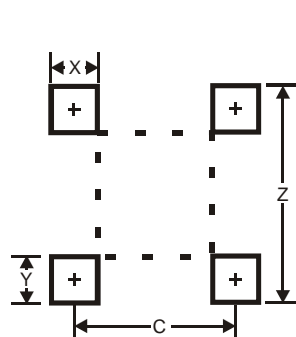
Please see <http://www.diodes.com/package-outlines.html> for the latest version.



DF-S		
Dim	Min	Max
A	7.40	7.90
B	6.20	6.50
C	0.22	0.30
D	0.076	0.33
E	—	10.40
G	1.02	1.53
H	8.13	8.51
J	2.40	2.60
K	5.00	5.20
L	1.00	1.20
All Dimensions in mm		

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Dimensions	Value (in mm)
Z	10.26
X	1.2
Y	1.52
C	5.2